

## Switching Diodes

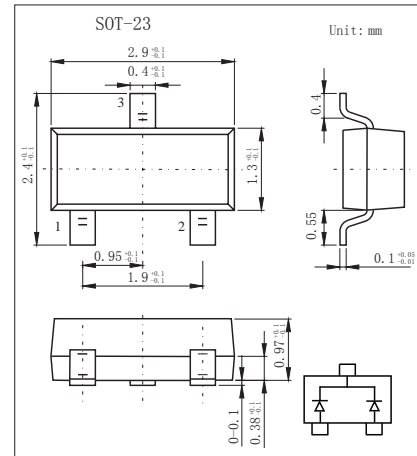
VOLTAGE RANGE: 70V  
PEAK PULSE POWER: 225mW

### Features

- Small plastic SMD package.
- High switching speed: max. 4 ns.
- Repetitive peak forward current: max. 450 mA.

### MECHANICAL DATA

- Case: SOT-23 Small Outline Plastic Package
- Polarity: Color band denotes cathode end
- Mounting Position: Any



## MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	V <sub>RRM</sub>	85	V
Continuous reverse voltage	V <sub>R</sub>	75	V
Continuous forward current (single diode loaded *) (double diode loaded *)	I <sub>F</sub>	215 125	mA
Repetitive peak forward current	I <sub>FRM</sub>	450	mA
Non-repetitive peak forward current T <sub>j</sub> =25 °C t=1 μs	I <sub>FSM</sub>	4	A
t=1ms		1	
t=1s		0.5	
power dissipation *	P <sub>D</sub>	250	mW
Thermal resistance from junction to tie-point	R <sub>th j-tp</sub>	360	K/W
Thermal resistance from junction to ambient *	R <sub>th j-a</sub>	500	K/W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

\* Device mounted on an FR4 printed-circuit board.

## Electrical Specification (T<sub>A</sub>=25°C unless otherwise specified)

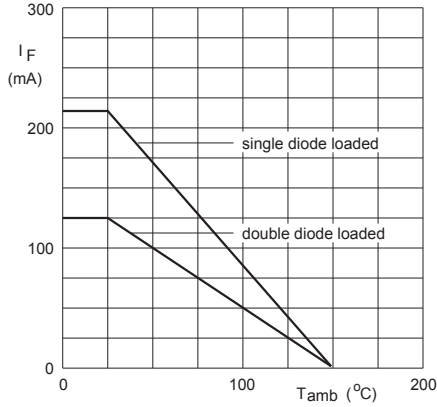
Parameter	Symbol	Test conditions	Max	Unit
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 1 mA	715	mV
		I <sub>F</sub> = 10 mA	855	mV
		I <sub>F</sub> = 50 mA	1	V
		I <sub>F</sub> = 150 mA	1.25	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> = 75 V	1	μA
		V <sub>R</sub> = 25 V; T <sub>j</sub> = 150 °C	30	
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	50	
Diode capacitance	C <sub>d</sub>	V <sub>R</sub> = 0 V, f = 1 MHz	1.5	pF
Reverse recovery time	t <sub>rr</sub>	when switched from I <sub>F</sub> = 10 mA to I <sub>R</sub> = 10 mA; R <sub>L</sub> = 100 Ω; measured at I <sub>R</sub> = 1 mA	4	nS
Forward recovery voltage	V <sub>fr</sub>	I <sub>F</sub> = 10 mA, t <sub>r</sub> = 20 ns	1.75	V

### Marking

Marking	A4
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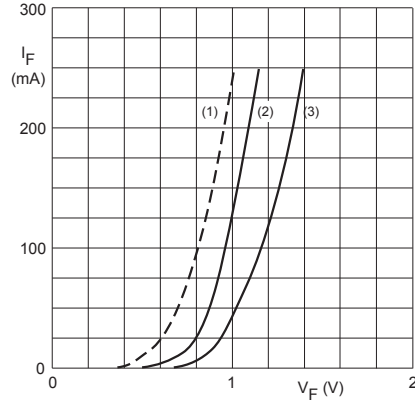
# RATINGS AND CHARACTERISTIC CURVES

## ■ Typical Characteristics



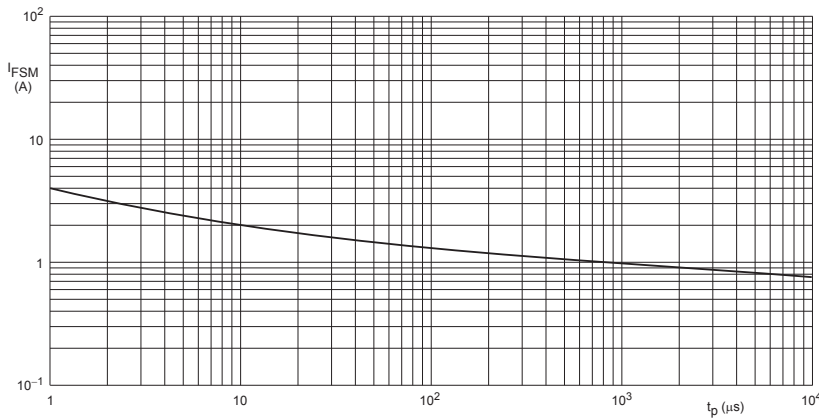
Device mounted on an FR4 printed-circuit board.

Fig.1 Maximum permissible continuous forward current as a function of ambient temperature.



- (1)  $T_j = 150^{\circ}C$ ; typical values.
- (2)  $T_j = 25^{\circ}C$ ; typical values.
- (3)  $T_j = 25^{\circ}C$ ; maximum values.

Fig.2 Forward current as a function of forward voltage.



Based on square wave currents.  
 $T_j = 25^{\circ}C$  prior to surge.

Fig.3 Maximum permissible non-repetitive peak forward current as a function of pulse duration.

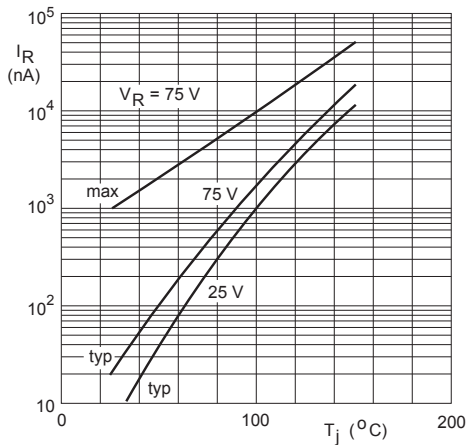
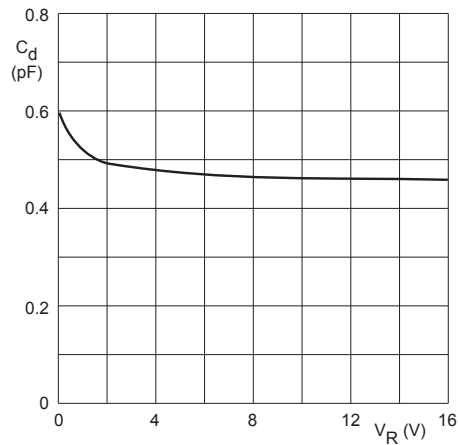


Fig.4 Reverse current as a function of junction temperature.



$f = 1$  MHz;  $T_j = 25^{\circ}C$ .

Fig.5 Diode capacitance as a function of reverse voltage; typical values.